

Electronic Supplementary Material (ESI) for Nanoscale Horizons.
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SUPPORTING INFORMATION

Highly stable Pd/HNb₃O₈-based flexible humidity sensor for perdurable wireless wearable applications

Yuyao Lu^a, Kaichen Xu^a, Min-Quan Yang^b, Shin-Yi Tang^c, Tzu-Yi Yang^c, Yusuke Fujita^a, Satoko Honda^a, Takayuki Arie^a, Seiji Akita^a, Yu-Lun Chueh^c, and Kuniharu Takei^{*a,d}

- a. Department of Physics and Electronics, Osaka Prefecture University Sakai, Osaka 599-8531, Japan.*
- b. Fujian Key Laboratory of Pollution Control & Resource Reuse, College of Environmental Science and Engineering, Fujian Normal University Fuzhou, Fujian 350007, China.*
- c. Department of Materials Science and Engineering, National Tsing-Hua University Hsinchu 30013, Taiwan, R.O.C.*
- d. JST PRESTO, Kawaguchi, Saitama 332-0012, Japan.*

*Corresponding author: takei@pe.osakafu-u.ac.jp

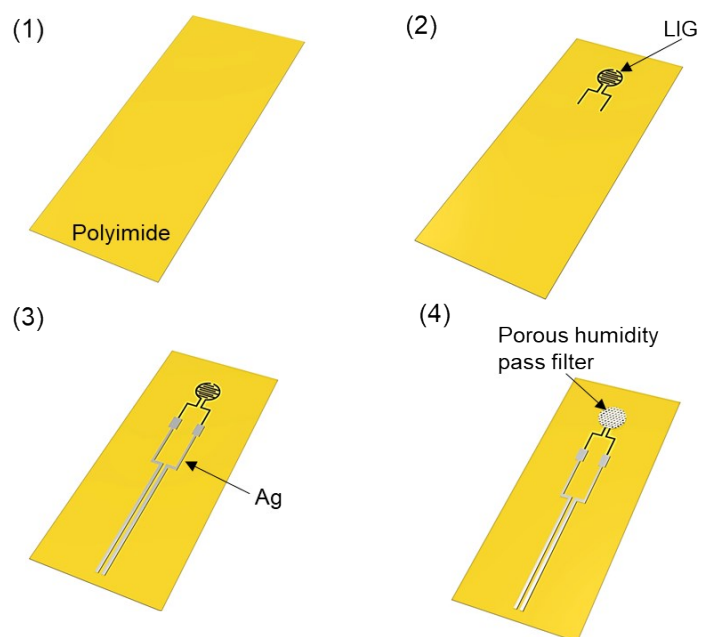


Figure S1. Schematics of the fabrication processes for the Pd/HNb₃O₈ humidity sensor.

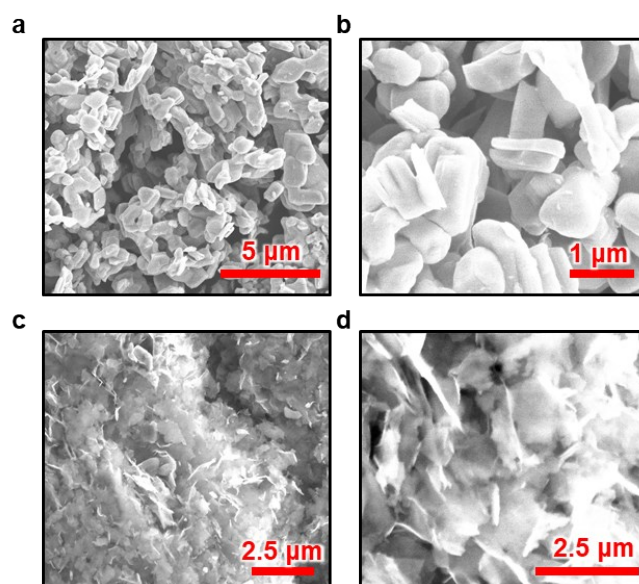


Figure S2. SEM images of (a)–(b) bulk HNb₃O₈ and (c)–(d) pristine HNb₃O₈ nanosheets.

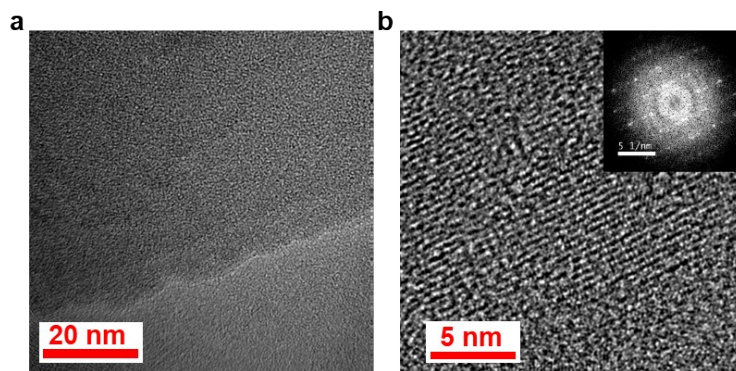


Figure S3. (a)(b) TEM images of HNb_3O_8 nanosheets.

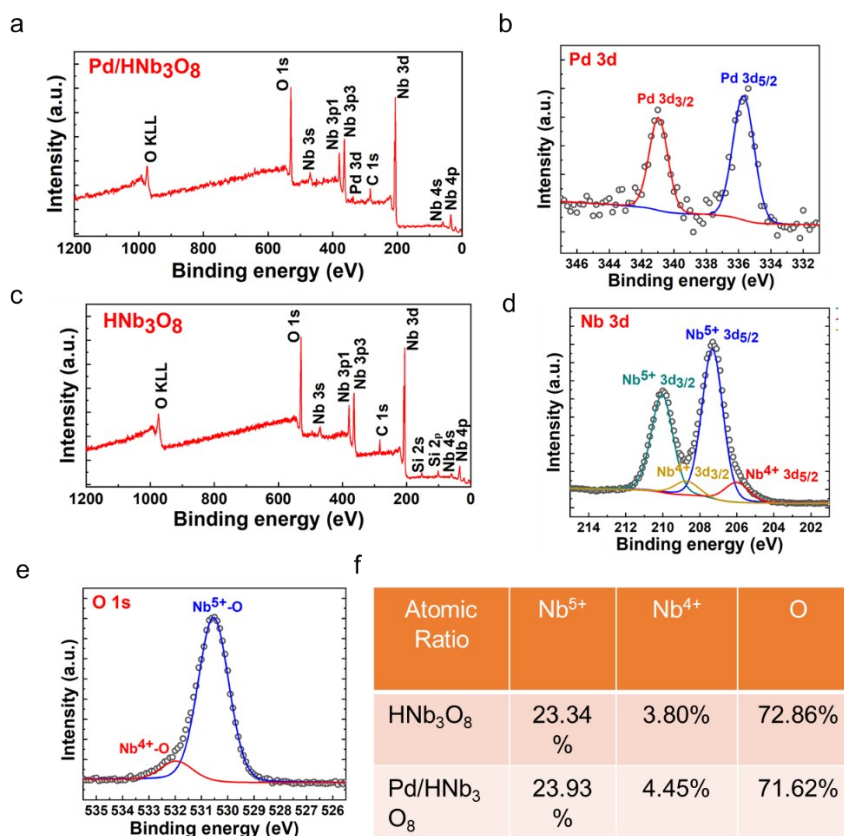


Figure S4. (a) XPS survey spectrum and (b) Pd 3d spectrum of $\text{Pd}/\text{HNb}_3\text{O}_8$ nanosheets. (c) XPS survey spectrum. (d) Nb 3d and (e) O 1s spectra of pristine HNb_3O_8 nanosheets. (f) Table of the atomic ratios of Nb^{5+} , Nb^{4+} and O in HNb_3O_8 and $\text{Pd}/\text{HNb}_3\text{O}_8$.

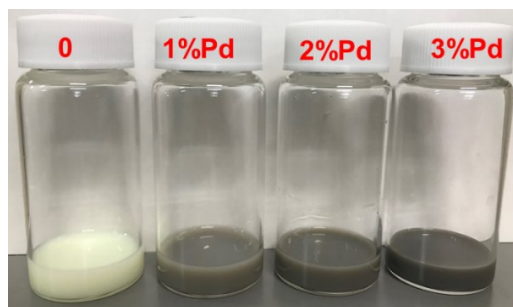


Figure S5. Photo of Pd/HNb₃O₈ nanosheets solution with different Pd contents.

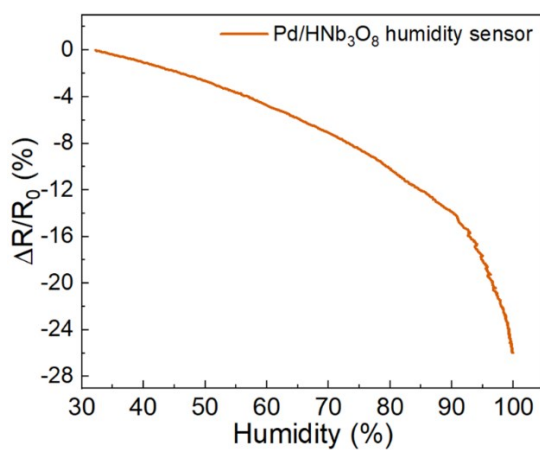


Figure S6. Sensitivity test of Pd/HNb₃O₈ humidity sensor at humidity variation from 30% to 99.9%.

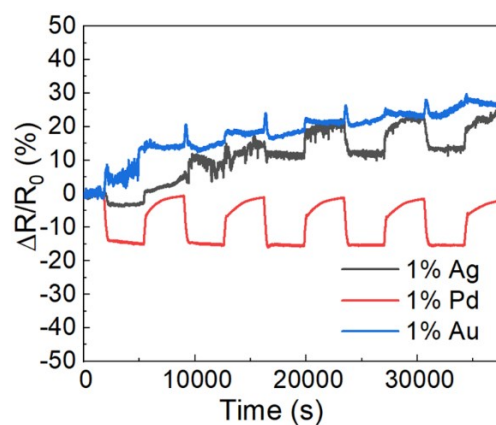


Figure S7. Short cycle tests of Ag/Pd/Au-modified HNb_3O_8 humidity sensors.

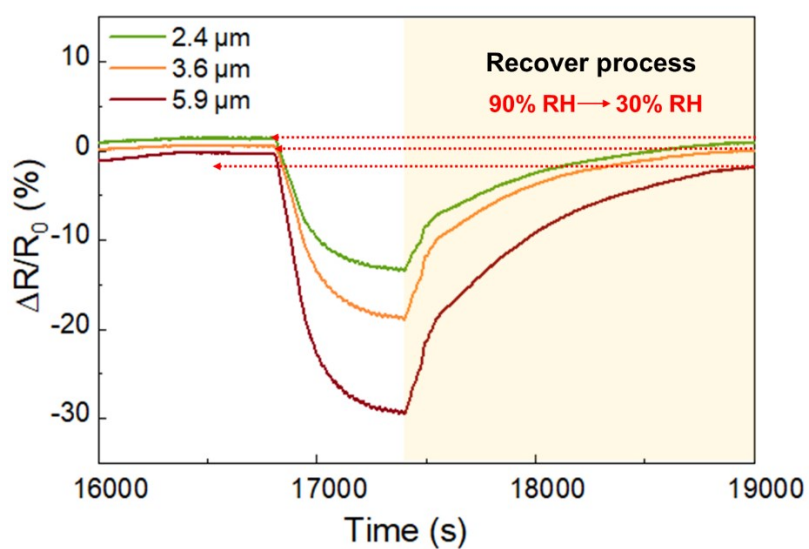


Figure S8. The response and recover result of humidity sensors fabricated with different thicknesses of Pd/ HNb_3O_8 nanosheets.

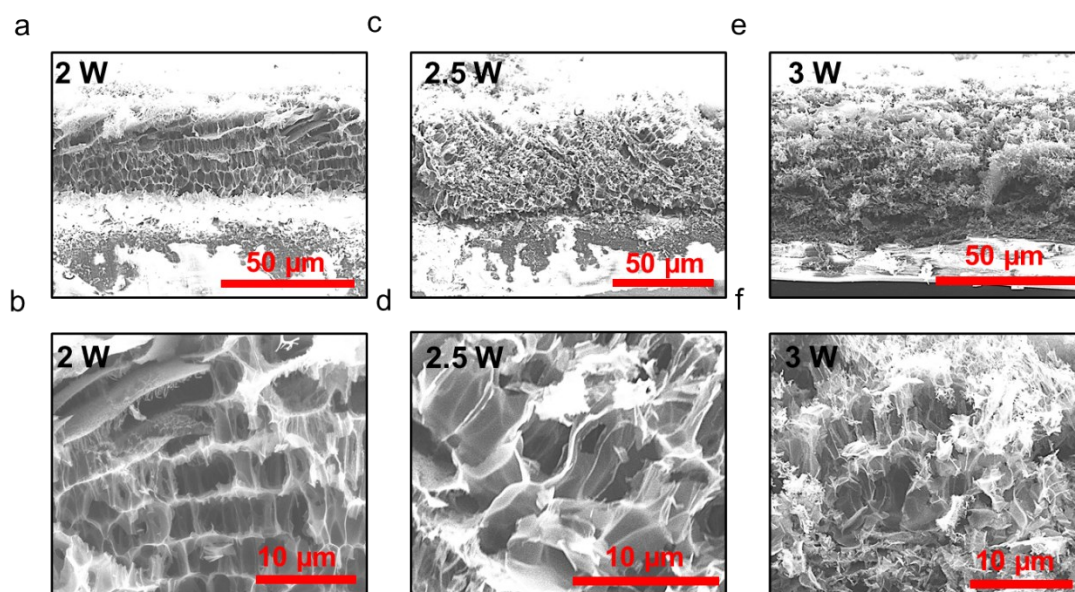


Figure S9. Cross-sectional SEM images of LIG generated in different laser powers at (a–b) 2 W, (c–d) 2.5 W, and (e–f) 3 W.

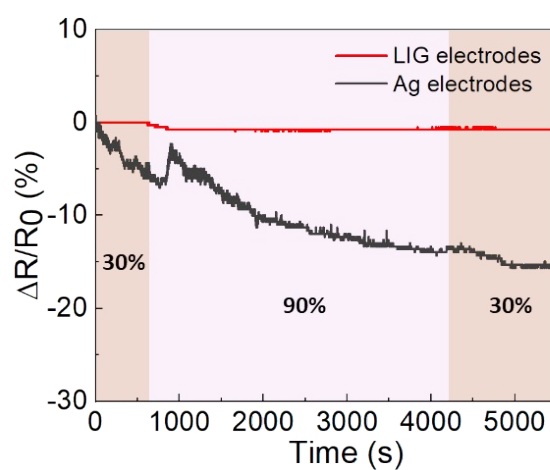


Figure S10. Resistance change of LIG electrodes and Ag electrodes under humidity changes from 30% to 90%.

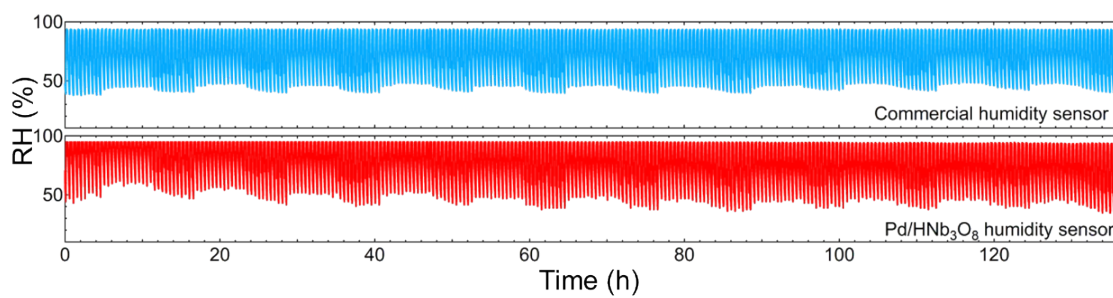


Figure S11. 273 cycles of tests at humidity variation from 50% to 90%.

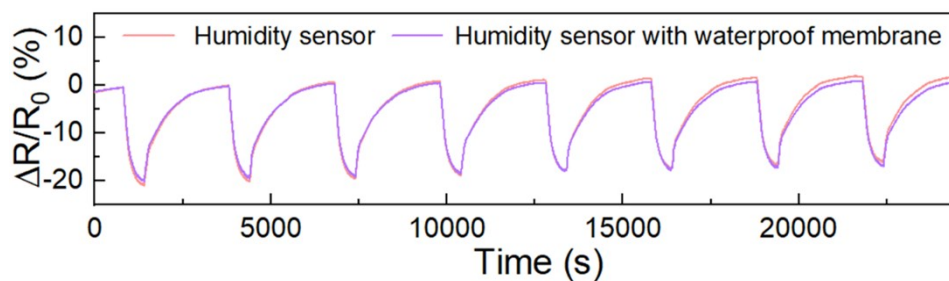


Figure S12. Cycle tests of a Pd/HNb₃O₈ humidity sensor with and without a porous humidity pass filter.

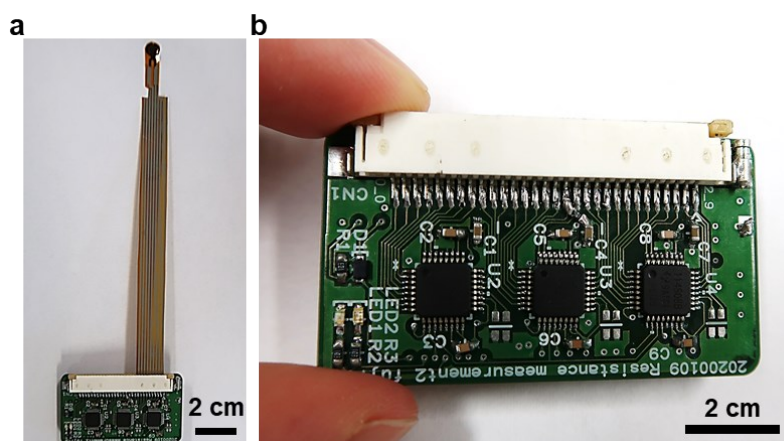


Figure S13. (a) Photo of a humidity sensor connected with a microcontroller and wireless circuit. (b) Magnified photo of the circuit.

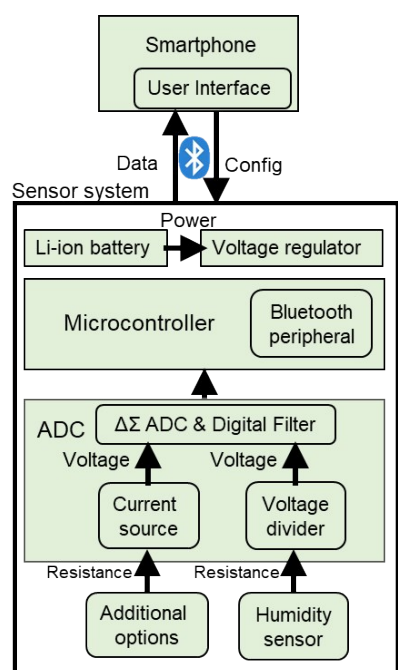


Figure S14. Circuit diagram of wireless communication.

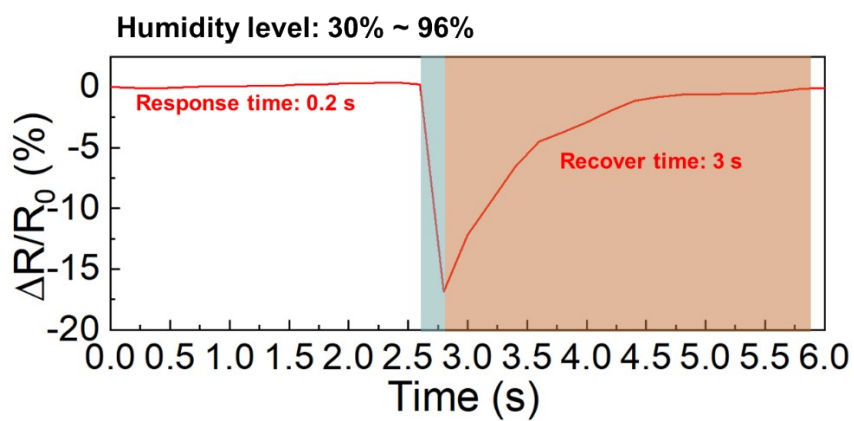


Figure S15. Response and recovery times of a short breathing test.

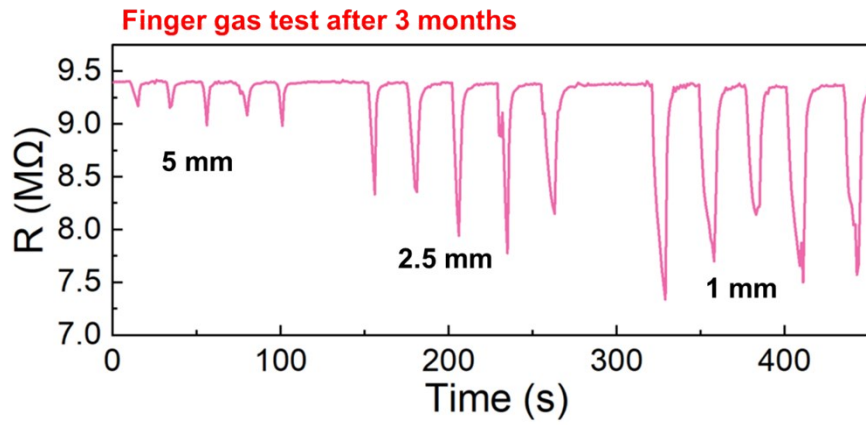


Figure S16. The repeated finger moisture detection under different gap distances after 3 months.

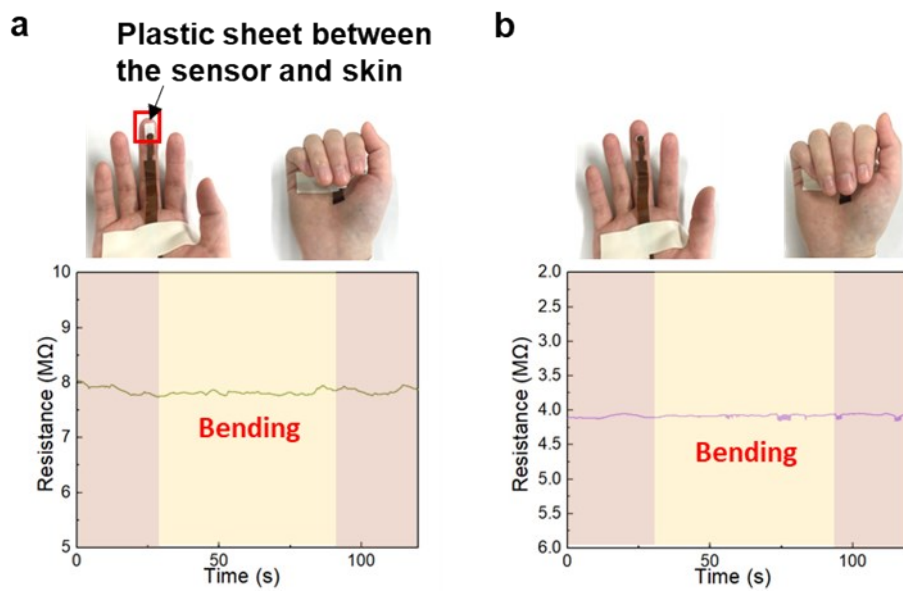


Figure S17. Real-time bending result of a humidity sensor placed on the finger of a subject (a) without and (b) with moisture contact.

Table S1. Comparison of different material-based humidity sensors.

Sensing materials	Detection range	Sensitivity at highest RH ($\Delta R/R_0$)	Response /recover time	Cycling number/duration time at high RH	refs
Pt/nRGO fiber	6.1%-66.4%	4.51%	—	—	Choi et al. ¹
Porous graphene	12%-97%	3.21%	31 s/72 s	5/5000 s at 59% RH	Pang et al. ²
MoS ₂	0-35%	10 ⁴	10 s/60 s	5/500 s at 10% RH	Zhao et al. ³
VS ₂ nanosheets	1-100%	—	30-40 s/12-50 s	4/60 s at 60% RH	Feng et al. ⁴
WS ₂	11%-97%	469%	12 s/13 s	4/250 s at 97.3% RH	Pawbake et al. ⁵
MoO ₃	0-100%	10 ⁴	0.5 s/2 s	5/<15 s at 40% RH	Yang et al. ⁶
SnS ₂ /RGO	0-97%	—	4 s/3 s for 33% RH, 6 s/15 s for 97% RH	5/600 s at 97% RH	Zhang et al. ⁷
P4VP film	11%-95%	—	2.3 s/22.1 s	7/480 s at 95% RH	Dai et al. ⁸
Polysaccharide	11%-95%	4241.7%	29 ms/—	6/200 s at 95% RH	Wang et al. ⁹
H-Pd/HNb ₃ O ₈ nanosheets	30%-99%	30%	0.2 s/3 s	273/137 h at 90% RH	This work

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